



FUKUCOM COMPANY LTD.

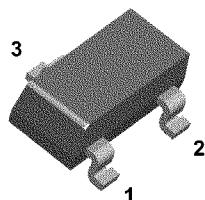
福靈有限公司

FLAT P, 3/F, EVEREST INDUSTRIAL CENTRE, 396 KWUN TONG ROAD,  
KWUN TONG, KOWLOON, HONG KONG.  
TEL: 2790-0314 FAX: 2790-0206

BAV23S

**FAIRCHILD**  
SEMICONDUCTOR®

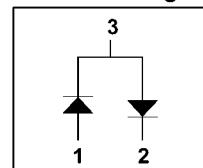
## BAV23S



SOT-23



Connection Diagram



### Small Signal Diode

#### Absolute Maximum Ratings\* T<sub>A</sub> = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>RRM</sub>	Maximum Repetitive Reverse Voltage	250	V
I <sub>F(AV)</sub>	Average Rectified Forward Current	200	mA
I <sub>FSM</sub>	Non-repetitive Peak Forward Surge Current Pulse Width = 1.0 microsecond Pulse Width = 100 microsecond	9.0 3.0	A A
T <sub>stg</sub>	Storage Temperature Range	-55 to +150	°C
T <sub>J</sub>	Operating Junction Temperature	150	°C

\*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

#### Thermal Characteristics

Symbol	Parameter	Value	Units
P <sub>D</sub>	Power Dissipation	350	mW
R <sub>θJA</sub>	Thermal Resistance, Junction to Ambient	357	°C/W

#### Electrical Characteristics T<sub>A</sub> = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Max	Units
V <sub>R</sub>	Breakdown Voltage	I <sub>R</sub> = 100 μA	250		V
V <sub>F</sub>	Forward Voltage	I <sub>F</sub> = 100 mA I <sub>F</sub> = 200 mA		1.0 1.25	V
I <sub>R</sub>	Reverse Current	V <sub>R</sub> = 250 V V <sub>R</sub> = 250 V, T <sub>A</sub> = 150°C		100 100	nA μA
t <sub>rr</sub>	Reverse Recovery Time	I <sub>F</sub> = I <sub>R</sub> = 30 mA, I <sub>RR</sub> = 3.0 mA, R <sub>L</sub> = 100 Ω		50	ns



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### Small Signal Diode

(continued)

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#### Typical Characteristics

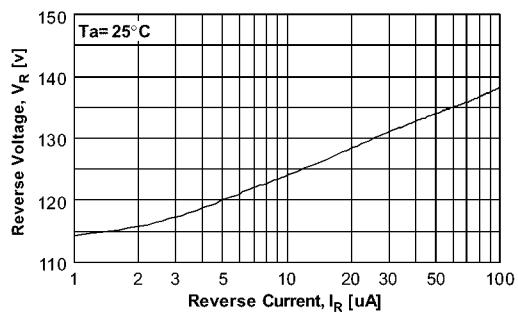


Figure 1. Reverse Voltage vs Reverse Current  
BV - 1.0 to 100  $\mu A$

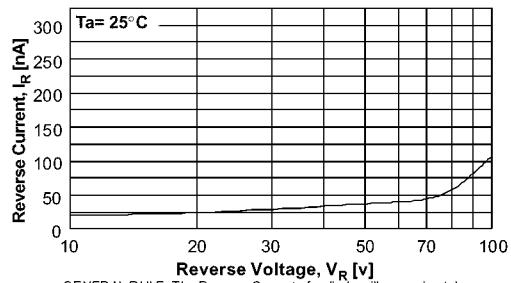


Figure 2. Reverse Current vs Reverse Voltage  
IR - 10 to 100 V

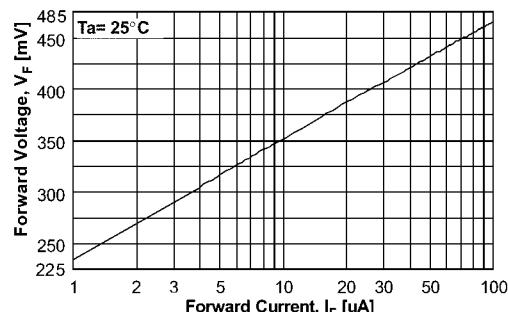


Figure 3. Forward Voltage vs Forward Current  
VF - 1.0 to 100  $\mu A$

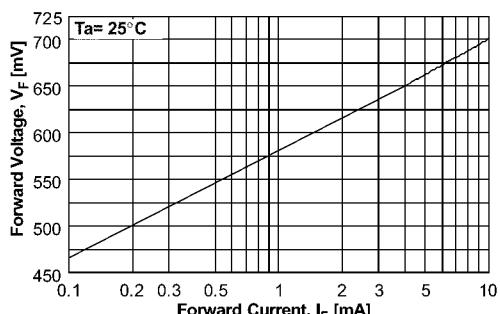


Figure 4. Forward Voltage vs Forward Current  
VF - 0.1 to 10 mA

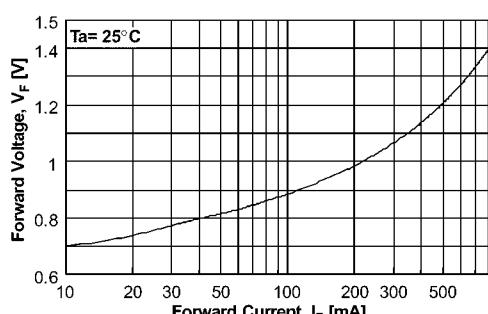


Figure 5. Forward Voltage vs Forward Current  
VF - 10 - 800 mA

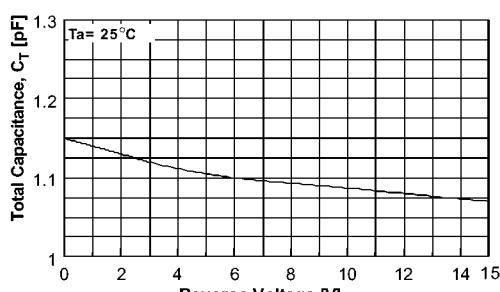


Figure 6. Total Capacitance



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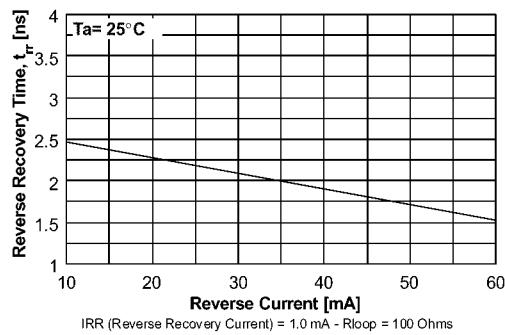
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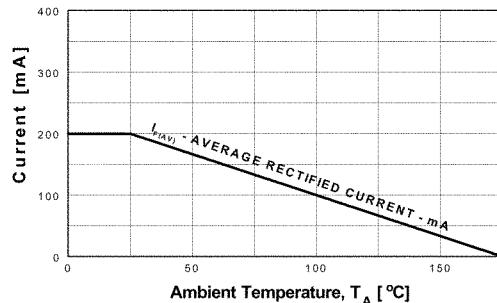
**Small Signal Diode**  
(continued)

B  
AV23S

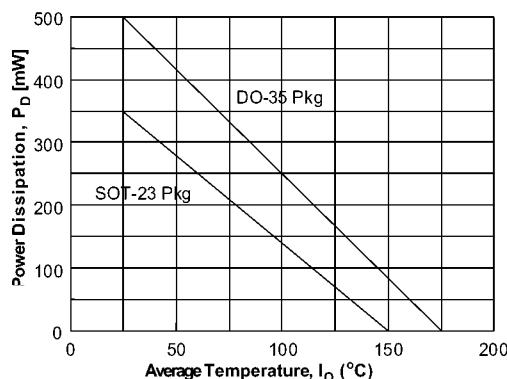
**Typical Characteristics** (continued)



**Figure 7. Reverse Recovery Time  
vs Reverse Current**  
TRR - IR 10 mA vs 60 mA



**Figure 8. Average Rectified Current (I<sub>F(AV)</sub>)  
versus Ambient Temperature (T<sub>A</sub>)**



**Figure 9. Power Derating Curve**